

TOSHIBA

TOSHIBA Original CMOS 8-Bit Microcontroller

TLCS-870 Series

TMP87PP21FG

TMP87PP21DFG

Not Recommended
for New Design

TOSHIBA CORPORATION

Semiconductor Company

Document Change Notification

The purpose of this notification is to inform customers about the launch of the Pb-free version of the device. The introduction of a Pb-free replacement affects the datasheet. Please understand that this notification is intended as a temporary substitute for a revision of the datasheet.

Changes to the datasheet may include the following, though not all of them may apply to this particular device.

1. Part number

Example: TMPxxxxxxF TMPxxxxxxFG

All references to the previous part number were left unchanged in body text. The new part number is indicated on the prelims pages (cover page and this notification).

2. Package code and package dimensions

Example: LQFP100-P-1414-0.50C LQFP100-P-1414-0.50F

All references to the previous package code and package dimensions were left unchanged in body text. The new ones are indicated on the prelims pages.

3. Addition of notes on lead solderability

Now that the device is Pb-free, notes on lead solderability have been added.

4. RESTRICTIONS ON PRODUCT USE

The previous (obsolete) provision might be left unchanged on page 1 of body text. A new replacement is included on the next page.

5. Publication date of the datasheet

The publication date at the lower right corner of the prelims pages applies to the new device.

1. Part number
2. Package code and dimensions

Previous Part Number (in Body Text)	Previous Package Code (in Body Text)	New Part Number	New Package Code	OTP
TMP87PP21F	P-QFP80-1420-0.80B	TMP87PP21FG	QFP80-P-1420-0.80B	—
TMP87PP21DF	P-LQFP80-1212-0.50A	TMP87PP21DFG	LQFP80-P-1212-0.50E	—

*: For the dimensions of the new package, see the attached Package Dimensions diagram.

3. Addition of notes on lead solderability

The following solderability test is conducted on the new device.

Lead solderability of Pb-free devices (with the G suffix)

Test	Test Conditions	Remark
Solderability	(1) Use of Lead (Pb) ·solder bath temperature = 230°C ·dipping time = 5 seconds ·the number of times = once ·use of R-type flux (2) Use of Lead (Pb)-Free ·solder bath temperature = 245°C ·dipping time = 5 seconds ·the number of times = once ·use of R-type flux	Leads with over 95% solder coverage till lead forming are acceptable.

4. RESTRICTIONS ON PRODUCT USE

The following replaces the “RESTRICTIONS ON PRODUCT USE” on page 1 of body text.

RESTRICTIONS ON PRODUCT USE

20070701-EN

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- For a discussion of how the reliability of microcontrollers can be predicted, please refer to Section 1.3 of the chapter entitled Quality and Reliability Assurance/Handling Precautions.

5. Publication date of the datasheet

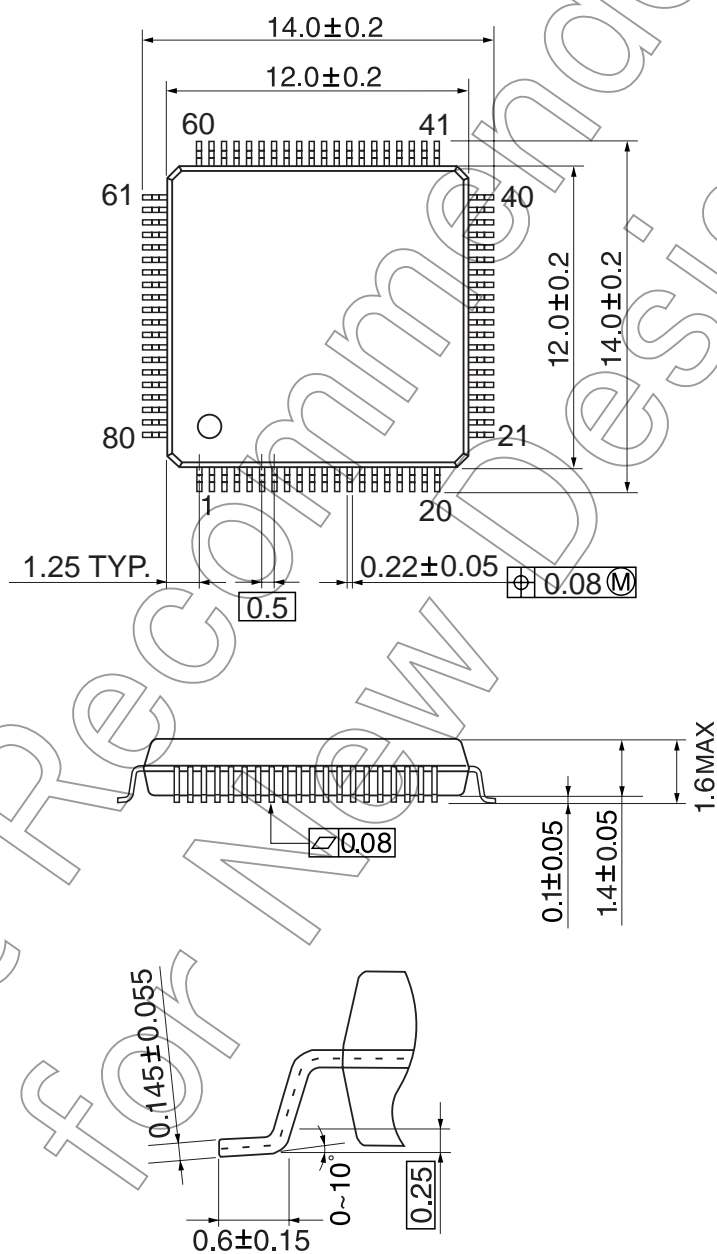
The publication date of this datasheet is printed at the lower right corner of this notification.

(Annex)

Package Dimensions

LQFP80-P-1212-0.50E

Unit: mm

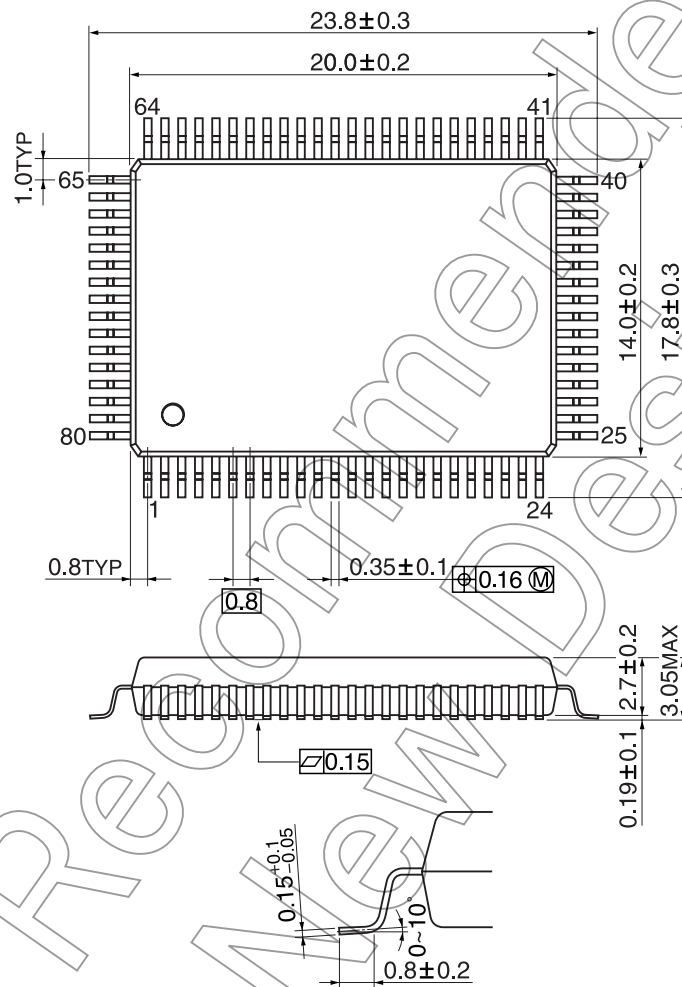


(Annex)

Package Dimensions

QFP80-P-1420-0.80B

Unit: mm



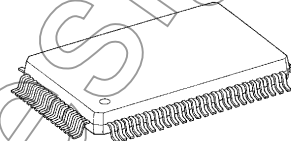
CMOS 8-Bit Microcontroller

TMP87PP21F **TMP87PP21DF**

The TMP87PP21 is a One-Time PROM microcontroller with low-power 48 K × 8 bits electrically programmable read only memory for the TMP87CH21C/M21C/P21C system evaluation. The TMP87PP21 is pin compatible with the TMP87CH21C/M21C/P21C. The operations possible with the TMP87CH21C/M21C/P21C can be performed by writing programs to PROM. The TMP87PP21 can write and verify in the same way as the TC571000D using an adaptor socket BM11104/BM11105 and an EPROM programmer.

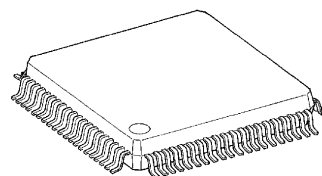
Product No.	OTP	RAM	Package	OTP Adapter
TMP87PP21F	48 K × 8 bits	2 K × 8 bits	P-QFP80-1420-0.80B	BM11104
TMP87PP21DF			P-LQFP80-1212-0.50A	BM11105

P-QFP80-1420-0.80B



TMP87PP21F

P-LQFP80-1212-0.50A



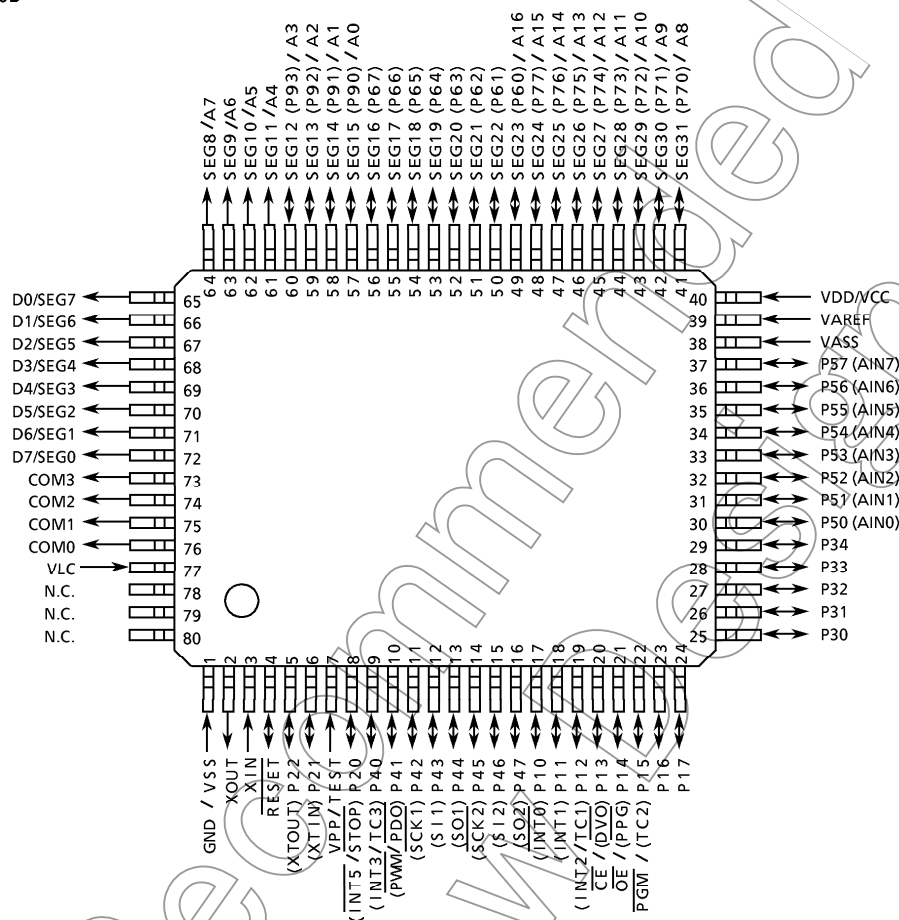
TMP87PP21DF

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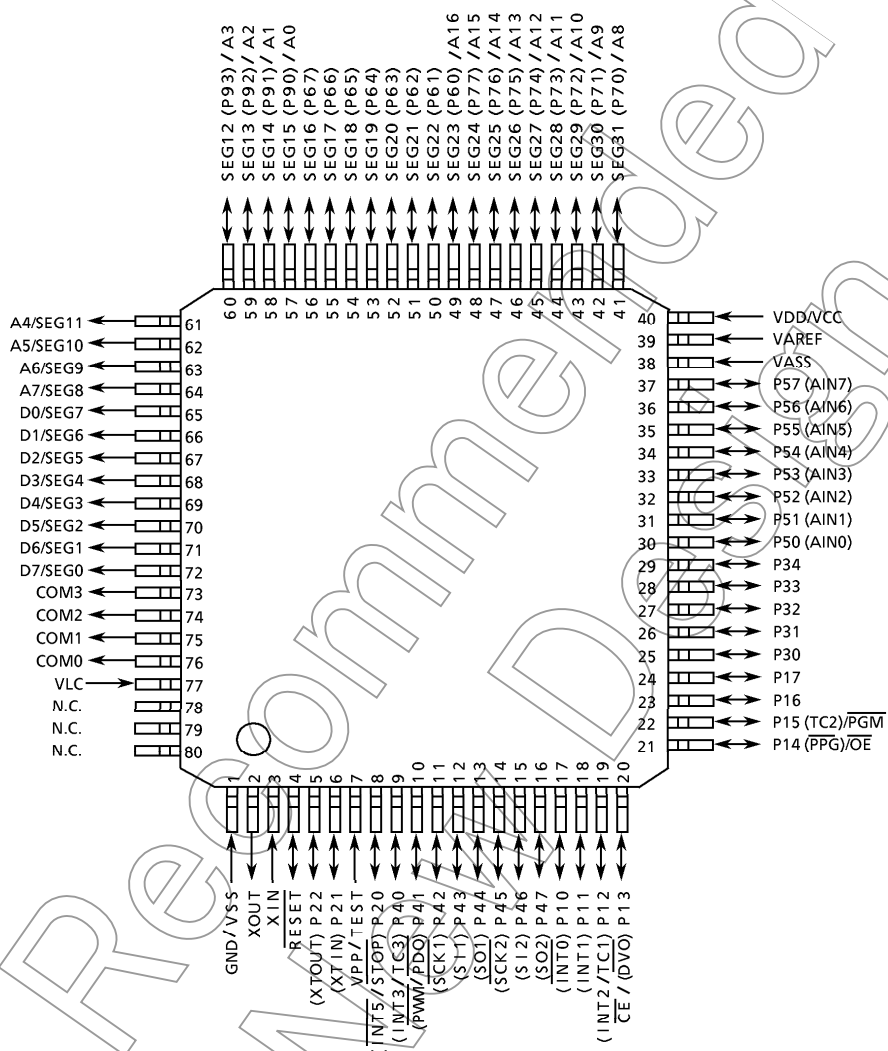
Pin Assignments (Top View)

P-QFP80-1420-0.80B



Note: Always keep N.C. pins open.

P-LQFP80-1212-0.50A



Note: Always keep N.C. pins open.

Pin Functions

The TMP87PP21 has two modes: MCU and PROM.

(1) MCU mode

In this mode, the TMP87PP21 is pin compatible with the TMP87CH21C/M21C/P21C (fix the TEST pin at low level.)

(2) PROM mode

Pin Name (PROM mode)	Input/Output	Functions	Pin Name (MCU mode)	
A16	Input	PROM address inputs	P60	
A15 to A8			P77 to P70	
A7 to A0			SEG8 to 11, P93 to P90	
D7 to D0	I/O	PROM data input/outputs	SEG0 to SEG7	
\overline{CE}	Input	Chip enable signal input (active low)	P13	
\overline{OE}		Output enable signal input (active low)	P14	
\overline{PGM}		Program mode signal input	P15	
VPP	Power supply	+ 12.75 V/5 V (Program supply voltage)	TEST	
VCC		+ 6.25 V/5 V	VDD	
GND		0 V	VSS	
P37 to P32, P30		Pull-up with resistance for input processing.		
P47 to P40				
P57 to P50				
P67 to P62				
P11	I/O	PROM mode setting pin. Be fixed at high level.		
P21				
P31				
P61		PROM mode setting pin. Be fixed at low level.		
P17, P16, P12, P10				
P22, P20				
RESET				
XIN	Input	Connect an 8 MHz oscillator to stabilize the internal state.		
XOUT	Output			
VAREF	Power supply	0 V (GND)		
VASS				
COM3 to COM0	Output	Open		
VLC	LCD driver Power supply			

Operational Description

The following explains the TMP87PP21 hardware configuration and operation. The configuration and functions of the TMP87PP21 are the same as those of the TMP87CH21C/M21C/P21C, except in that a one-time PROM is used instead of an on-chip mask ROM.

The TMP87PP21 is placed in the *single-clock* mode during reset. To use the dual-clock mode, the low-frequency oscillator should be turned on by executing [SET (SYSCR2). XTEN] instruction at the beginning of the program.

1. Operating Mode

The TMP87PP21 has two modes: MCU and PROM.

1.1 MCU mode

The MCU mode is activated by fixing the TEST/VPP pin at low level.

In the MCU mode, operation is the same as with the TMP87CH21C/M21C/P21C (the TEST/VPP pin cannot be used open because it has no built-in pull-down resistance).

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1.1.1 Program Memory

The TMP87PP21 has a 48K × 8 bits (addresses 4000_H to FFFF_H in the MCU mode, addresses 14000_H to 1FFFF_H in the PROM mode) of program memory (OTP).

When the TMP87PP21 is used as a system evaluation of the TMP87CH21C/M21C/P21C, the data is written to the program storage area shown in Figure 1-1.

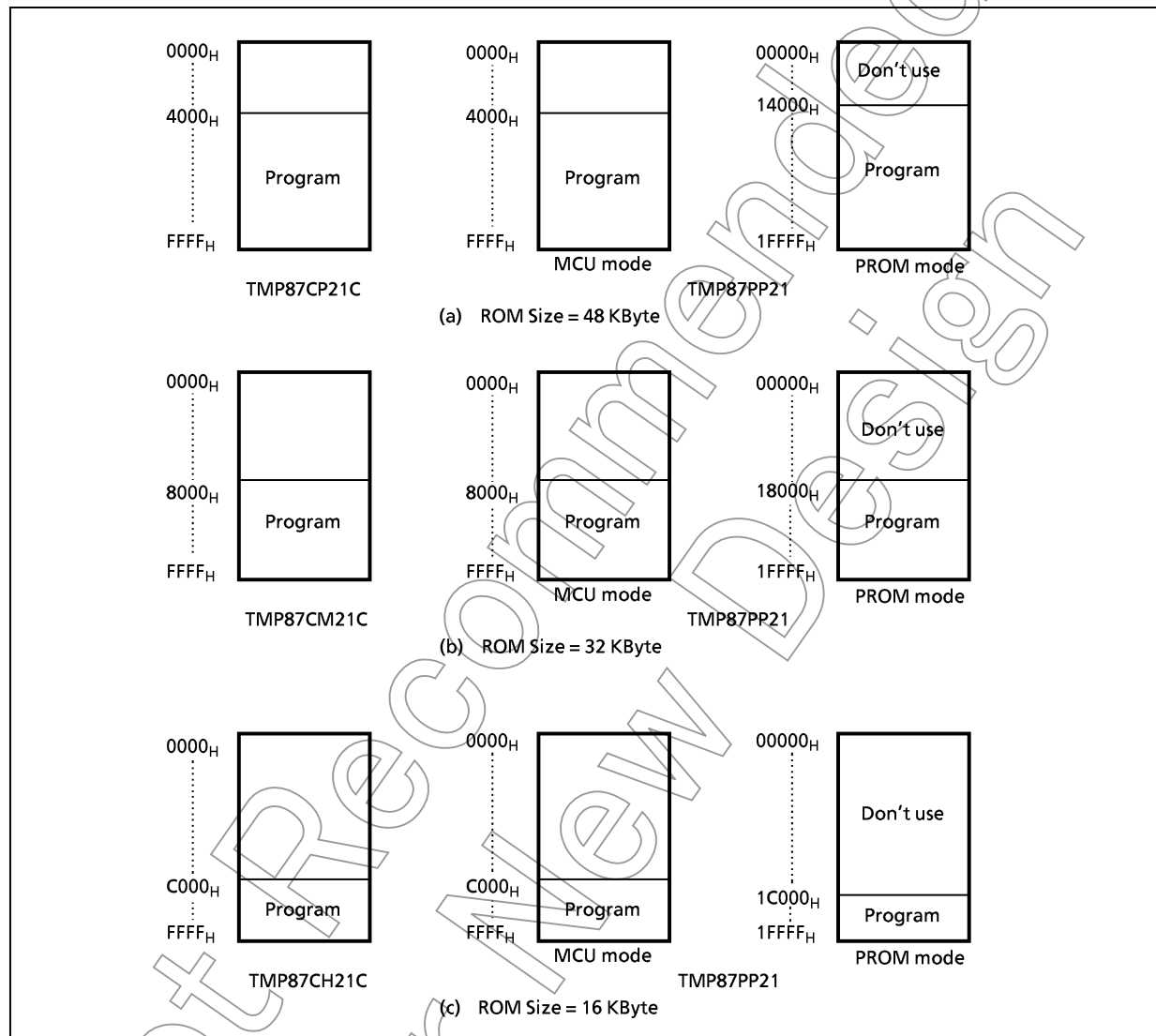


Figure 1-1. Program Storage Area

Note: Either write the data FF_H to the unused area or set the PROM programmer to access only the program storage area.

1.1.2 Data Memory

The TMP87PP21 has an on-chip 2 K × 8 bits data memory (static RAM).

1.1.3 Input/Output Circuitry

(1) Control pins

The control pins of the TMP87PP21 are the same as those of the TMP87CH21C/M21C/P21C except that the TEST pin has no built-in pull-down resistance.

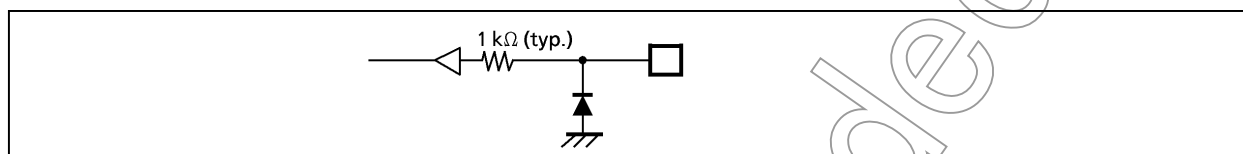


Figure 1-2. TEST pin

(2) I/O ports

The I/O circuitries of the TMP87PP21 I/O ports are the same as circuitries of the TMP87CH21C/M21C/P21C.

1.2 PROM Mode

The PROM mode is activated by setting the TEST, $\overline{\text{RESET}}$ pin and the ports P17 to P10, P22 to P20 and P31, P61 as shown in Figure 1-3. The PROM mode is used to write and verify programs with a general-purpose PROM programmer.

Note: The high-speed programming mode can be used for program operation. (Please set the high-speed programming mode according to each manual of PROM programmer.)
The TMP87PP21 is not supported an electric signature mode, so the ROM type must be set to TC571000D.

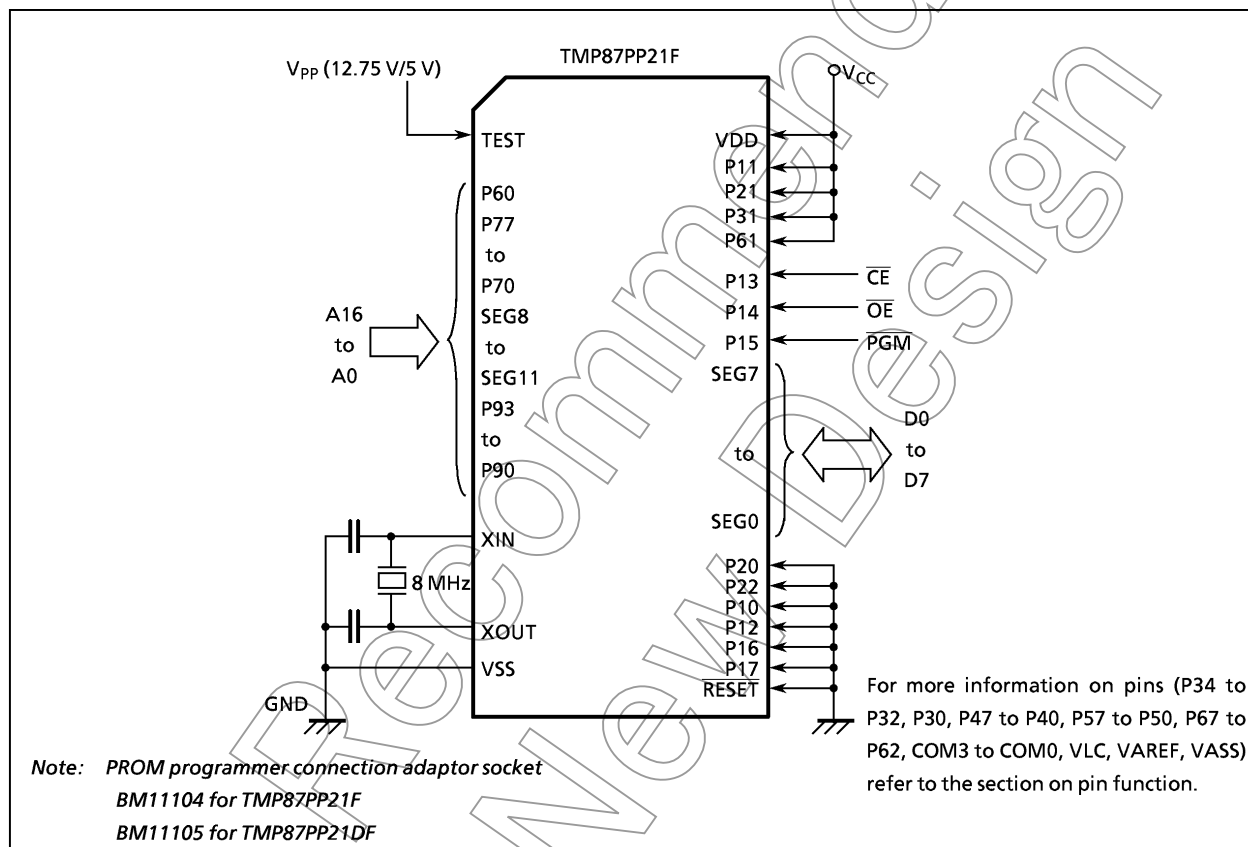


Figure 1-3. Setting for PROM Mode

1.2.1 Programming Flowchart (High-speed Programming Mode)

The high-speed programming mode is achieved by applying the program voltage (+ 12.75 V) to the VPP pin when $V_{CC} = 6.25$ V. After the address and input data are stable, the data is programmed by applying a single 0.1ms program pulse to the PGM input. The programmed data is verified. If incorrect, another 0.1 ms program pulse is applied. This process should be repeated (up to 25 times) until the program operates correctly. After that, change the address and input data, and program as before. When programming has been completed, the data in all addresses should be verified with $V_{CC} = V_{PP} = 5$ V.

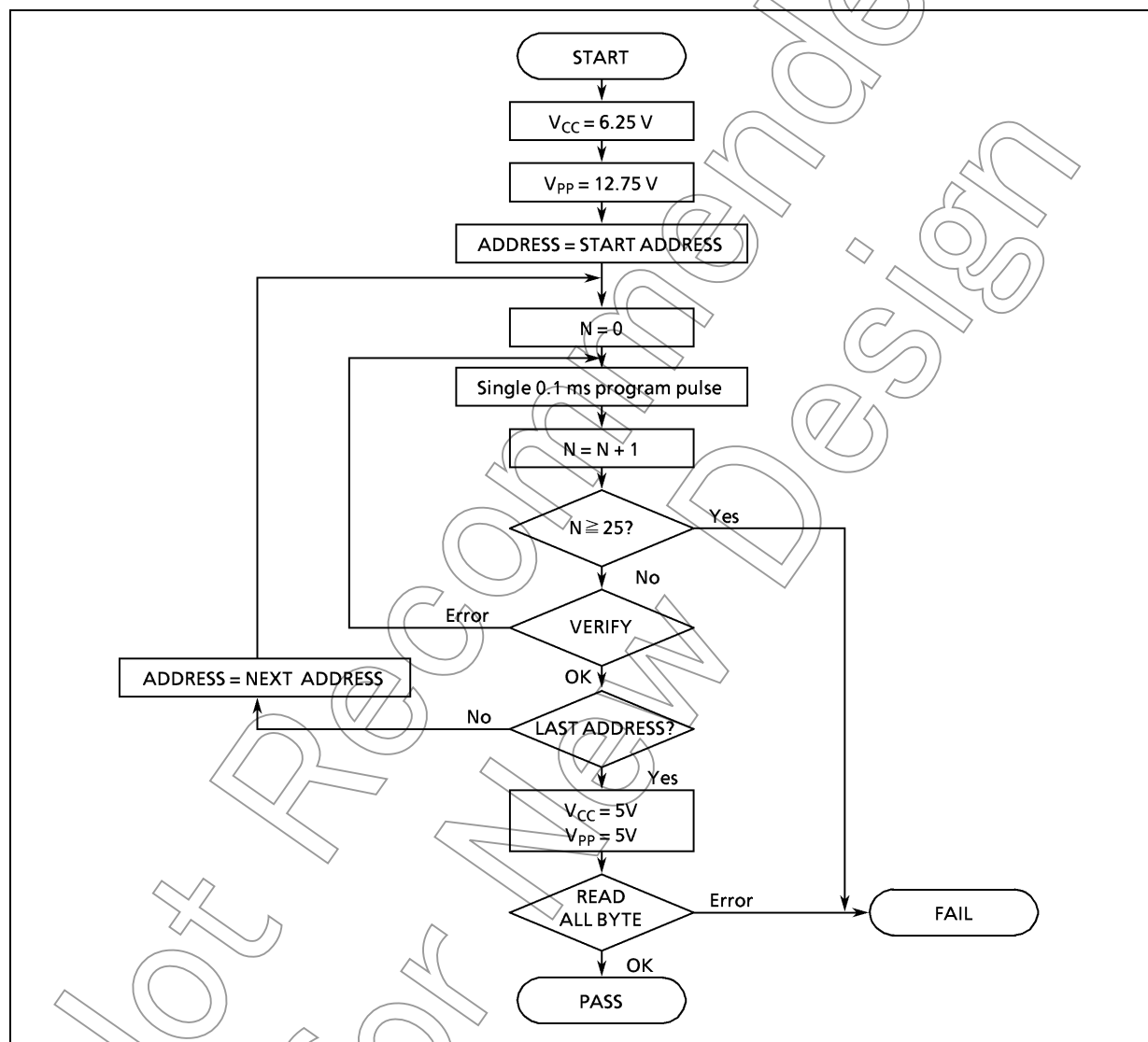


Figure 1-4. Flowchart of High-speed Programming

1.2.2 Writing Method for General-purpose PROM Program

(1) Adapters

BM11104: TMP87PP21F

BM11105: TMP87PP21DF

(2) Adapter setting

Switch (SW1) is set to side N.

(3) PROM programmer specifying

i) PROM type is specified to TC571000D.

Writing voltage: 12.75 V (high-speed program mode)

ii) Data transfer (copy) (Note 1)

In the TMP87PP21, EPROM is within the addresses 14000_H to 1FFFF_H. Data is required to be transferred (copied) to the addresses where it is possible to write. The program area in MCU mode and PROM mode is referred to "Program memory area" in Figure 1-1.

Ex. In the block transfer (copy) mode, executed as below.

ROM capacity of 48 KB: transferred addresses 04000_H to 0FFFF_H to addresses 14000 to 1FFFF_H

iii) Writing address is specified. (Note 1)

Start address: 14000_H

End address: 1FFFF_H

(4) Writing

Writing/Verifying is required to be executed in accordance with PROM programmer operating procedure.

Note 1: The specifying method is referred to the PROM programmer description. Either write the data FF_H to the unused area or set the PROM programmer to access only the program storage area.

Note 2: When MCU is set to an adapter or the adapter is set to PROM programmer, a position of pin 1 must be adjusted. If the setting is reversed, MCU, the adapter and PROM program is damaged.

Note 3: The TMP87PP21 does not support the electric signature mode (hereinafter referred to as "signature"). If the signature is used in PROM program, a device is damaged due to applying 12 V ± 0.5 V to the address pin 9 (A9). The signature must not be used.

Electrical Characteristics

Absolute Maximum Ratings		(V _{SS} = 0 V)		
Parameter	Symbol	Pins	Ratings	Unit
Supply Voltage	V _{DD}		– 0.3 to 6.5	V
Program Voltage	V _{PP}	TEST/V _{PP}	– 0.3 to 13.0	
Input Voltage	V _{IN}		– 0.3 to V _{DD} + 0.3	
Output Voltage	V _{OUT}		– 0.3 to V _{DD} + 0.3	
Output Current (Per 1 pin)	I _{OUT1}	Ports P0, P1, P2, P3, P5, P6, P7, P8, P9, P4 (except P41)	3.2	mA
	I _{OUT2}	P41	30	
Output Current (Total)	Σ I _{OUT1}	Ports P0, P1, P2, P3, P5, P6, P7, P8, P9, P4 (except P41)	120	
	Σ I _{OUT2}	P41	30	
Power Dissipation [T _{opr} = 70°C]	PD		350	mW
Soldering Temperature (time)	T _{sld}		260 (10 s)	°C
Storage Temperature	T _{stg}		– 55 to 125	
Operating Temperature	T _{opr}		– 30 to 70	

Note: The absolute maximum ratings are rated values which must not be exceeded during operation, even for an instant. Any one of the ratings must not be exceeded. If any absolute maximum rating is exceeded, a device may break down or its performance may be degraded, causing it to catch fire or explode resulting in injury to the user. Thus, when designing products which include this device, ensure that no absolute maximum rating value will ever be exceeded.

Recommended Operating Conditions			(V _{SS} = 0 V, T _{opr} = – 30 to 70°C)				
Parameter	Symbol	Pins	Conditions		Min	Max	Unit
Supply Voltage	V _{DD}		f _c = 8 MHz	NORMAL1, 2 mode	4.5	5.5	
				IDLE1, 2 mode			
			f _c = 4.2 MHz	NORMAL1, 2 mode	2.7		
				IDLE1, 2 mode			
			f _s = 32.768 kHz	SLOW mode			
				SLEEP mode			
				STOP mode	2.0		
Input High Voltage	V _{IH1}	Except hysteresis input	V _{DD} ≥ 4.5 V		V _{DD} × 0.70	V _{DD}	V
	V _{IH2}	Hysteresis input			V _{DD} × 0.75		
	V _{IH3}				V _{DD} < 4.5 V		
Input Low Voltage	V _{IL1}	Except hysteresis input	V _{DD} ≥ 4.5 V		0	V _{DD} × 0.30	
	V _{IL2}	Hysteresis input				V _{DD} × 0.25	
	V _{IL3}					V _{DD} < 4.5 V	
Clock Frequency	f _c	XIN, XOUT	V _{DD} = 4.5 to 5.5 V		0.4	8.0	MHz
			V _{DD} = 2.7 to 5.5 V			4.2	
	f _s	XTIN, XTOUT			30.0	34.0	kHz

Note 1: The recommended operating conditions for a device are operating conditions under which it can be guaranteed that the device will operate as specified. If the device is used under operating conditions other than the recommended operating conditions (supply voltage, operating temperature range, specified AC/DC values etc.), malfunction may occur. Thus, when designing products which include this device, ensure that the recommended operating conditions for the device are always adhered to.

Note 2: Clock frequency fc: Supply voltage range is specified in NORMAL1/2 mode and IDLE1/2 mode.

DC Characteristics

(V_{SS} = 0 V, T_{opr} = -30 to 70°C)

Parameter	Symbol	Pins	Conditions	Min	Typ.	Max	Unit
Hysteresis Voltage	V _{HS}	Hysteresis inputs		—	0.9	—	V
Input Current	I _{IN1}	TEST	V _{DD} = 5.5 V, V _{IN} = 5.5 V/0 V	—	—	± 2	μA
	I _{IN2}	Open drain ports and tri-state ports					
	I _{IN3}	RESET, STOP					
Input Low Current	I _{IL}	Push-pull ports	V _{DD} = 5.5 V, V _{IN} = 0.4 V	—	—	– 2	mA
Input Resistance	R _{IN2}	RESET		100	220	450	kΩ
Output Leakage Current	I _{LO}	Open drain ports Tri-state ports	V _{DD} = 5.5 V, V _{OUT} = 5.5 V	—	—	2	μA
Output High Voltage	V _{OH1}	Push-pull ports P4 ports	V _{DD} = 4.5 V, I _{OH} = – 200 μA	2.4	—	—	V
	V _{OH2}	Tri- state ports P1, P5 ports	V _{DD} = 4.5 V, I _{OH} = – 0.7 mA	4.1	—	—	
Output Low Voltage	V _{OL}	Except XOUT and P41	V _{DD} = 4.5 V, I _{OL} = 1.6 mA	—	—	0.4	
Output Low Current	I _{OL3}	P41	V _{DD} = 4.5 V, V _{OL} = 1.0 V	—	20	—	
Supply Current in NORMAL 1, 2 mode	I _{DD}		V _{DD} = 5.5 V f _c = 8 MHz f _s = 32.768 kHz V _{IN} = 5.3 V/0.2 V	—	12	18	mA
Supply Current in IDLE 1, 2 mode				—	6	10	
Supply Current in SLOW mode			V _{DD} = 3.0 V f _s = 32.768 kHz V _{IN} = 2.8 V/0.2 V LCD driver is not enable	—	30	60	μA
Supply Current in SLEEP mode				—	15	30	
Supply Current in STOP mode			V _{DD} = 5.5 V V _{IN} = 5.3 V/0.2 V	—	0.5	10	
Segment Output Low Resistance	R _{OS1}	SEG31 to SEG0	V _{DD} = 5 V V _{DD} – V _{LC} = 3 V	—	20	—	kΩ
Common Output Low Resistance	R _{OC1}	COM3 to COM0					
Segment Output High Resistance	R _{OS2}	SEG31 to SEG0					
Common Output High Resistance	R _{OC2}	COM3 to COM0					
Segment/Common Output Voltage	V _{O 2/3}	SEG31 to SEG0 and COM3 to COM0		3.8	4.0	4.2	V
	V _{O 1/2}			3.3	3.5	3.7	
	V _{O 1/3}			2.8	3.0	3.2	

Note 1: Typical values show those at T_{opr} = 25°C, V_{DD} = 5 V.

Note 2: Input Current; The current through pull-up or pull-down resistor is not included.

Note 3: I_{DD}: Except for I_{REF}Note 4: Output resistors R_{os}, R_{oc} indicate "on" when switching levels.Note 5: V_{O2/3} indicates an output voltage at the 2/3 level when operating in the 1/4 or 1/3 duty mode.Note 6: V_{O1/2} indicates an output voltage at the 1/2 level when operating in the 1/2 duty or static mode.Note 7: V_{O1/3} indicates an output voltage at the 1/3 level when operating in the 1/4 or 1/3 duty mode.Note 8: When using LCD, it is necessary to consider values of R_{os1/2} and R_{oc1/2}.Note 9: Times for SEG/COM output switching on: R_{os1}, R_{oc1}: 26/f_c, 2/f_s (s)R_{os2}, R_{oc2}: 1/(n, f_F)(1/n: duty, f_F: frame frequency)

AD Conversion Characteristics

(V_{SS} = 0 V, V_{DD} = 2.7 to 5.5 V, T_{opr} = –30 to 70°C)

Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
Analog Reference Voltage	V _{AREF}	V _{AREF} – V _{ASS} ≥ 2.5 V	2.7	–	V _{DD}	V
	V _{ASS}		V _{SS}	–	1.5	
Analog Input Voltage	V _{AIN}		V _{ASS}	–	V _{AREF}	
Analog Supply Current	I _{REF}	V _{AREF} = 5.5 V, V _{ASS} = 0.0 V	–	0.5	1.0	mA
Nonlinearity Error		V _{DD} = 5.0 V, V _{SS} = 0.0 V V _{AREF} = 5.000 V	–	–	± 1	LSB
Zero Point Error		V _{ASS} = 0.000 V or	–	–	± 1	
Full Scale Error		V _{DD} = 2.7 V, V _{SS} = 0.0 V V _{AREF} = 2.700 V	–	–	± 1	
Total Error		V _{ASS} = 0.000 V	–	–	± 2	

Note: Quantizing error is not contained in those errors.

AC Characteristics - 1

(V_{SS} = 0 V, V_{DD} = 4.5 to 5.5 V, T_{opr} = –30 to 70°C)

Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
Machine Cycle Time	t _{cy}	In NORMAL 1, 2 mode	0.5	—	10	μs
		In IDLE 1, 2 mode				
		In SLOW mode	117.6	—	133.3	
		In SLEEP mode				
High Level Clock Pulse Width	t _{WCH}	For external clock operation (XIN input), f _c = 8 MHz	62.5	—	—	ns
Low Level Clock Pulse Width	t _{WCL}					
High Level Clock Pulse Width	t _{WSH}	For external clock operation (XTIN input), f _s = 32.768 kHz	14.7	—	—	μs
Low Level Clock Pulse Width	t _{WSL}					

AC Characteristics - 2

(V_{SS} = 0 V, V_{DD} = 2.7 to 5.5 V, T_{opr} = –30 to 70°C)

Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
Machine Cycle Time	t _{cy}	In NORMAL 1, 2 mode	0.95	—	10	μs
		In IDLE 1, 2 mode				
		In SLOW mode	117.6	—	133.3	
		In SLEEP mode				
High Level Clock Pulse Width	t _{WCH}	For external clock operation (XIN input), f _c = 4.2 MHz	110	—	—	ns
Low Level Clock Pulse Width	t _{WCL}					
High Level Clock Pulse Width	t _{WSH}	For external clock operation (XTIN input), f _s = 32.768 kHz	14.7	—	—	μs
Low Level Clock Pulse Width	t _{WSL}					

Recommended Oscillating Condition-1

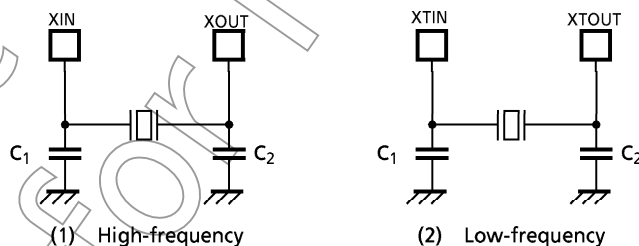
(VSS = 0 V, VDD = 4.5 to 5.5 V, Topr = -30 to 70°C)

Parameter	Oscillator	Frequency	Recommender Oscillator	Recommended Condition	
				C ₁	C ₂
High-frequency	Ceramic Resonator	8 MHz	KYOCERA KBR8.0M	30 pF	30 pF
			Standard/Lead Type (MURATA) CSA8.00MTZ CST8.00MTW	built-in 30 pF	built-in 30 pF
			Standard/SMP Type (MURATA) CSAC8.00MT	30 pF	30 pF
			Standard/Small Chip Type (MURATA) CSTC8.00MT	built-in 30 pF	built-in 30 pF
	Crystal Oscillator	4 MHz	KYOCERA KBR4.0MS	30 pF	30 pF
		8 MHz	TOYOCOM 210B 8.0000	20 pF	20 pF
Low-frequency	Crystal Oscillator	4 MHz	TOYOCOM 204B 4.0000		
		32.768 kHz	NDK MX-38T	15 pF	15 pF

Recommended Oscillating Condition-2

(VSS = 0 V, VDD = 2.7 to 5.5 V, Topr = -30 to 70°C)

Parameter	Oscillator	Frequency	Recommender Oscillator	Recommended Condition	
				C ₁	C ₂
High-frequency	Ceramic Resonator	4 MHz	Standard/Lead Type (MURATA) CSA4.00MG	30 pF	30 pF
			(MURATA) CST4.00MGW	built-in 30 pF	built-in 30 pF
			Standard/SMD Type (MURATA) CSA4.00MGC CSAC4.00MGCM CSTC4.00MG	30 pF	30 pF
				built-in 30 pF	built-in 30 pF
			Standard/Small Chip Type CSTCS4.00MG	built-in 10 pF	built-in 10 pF



Note1: When used in high electric field such as a picture tube, the package is recommended to be electrically shielded to maintain a regular operation.

Note2: The product numbers and specifications of the resonators by Murata Manufacturing Co., Ltd. are subject to change. For up-to-date information, please refer to the following URL;

<http://www.murata.co.jp/search/index.html>

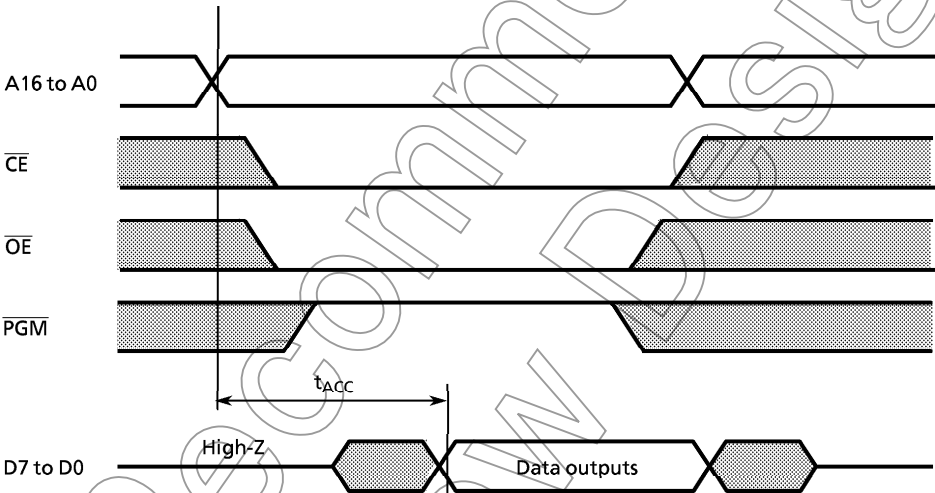
DC/AC Characteristics (PROM mode)

(V_{SS} = 0 V)

(1) Read Operation

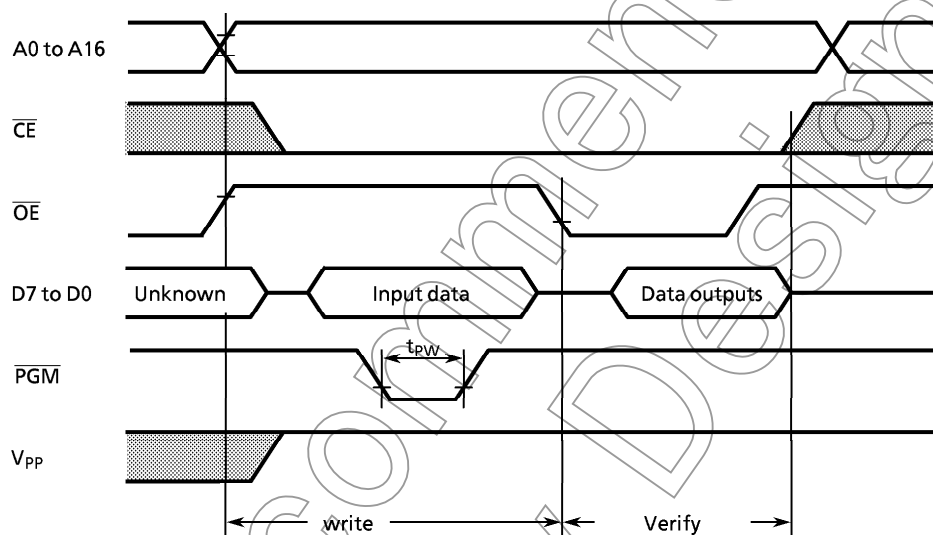
Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
Input High Voltage	V _{IH4}		V _{CC} × 0.7	—	V _{CC}	V
Input Low Voltage	V _{IL4}		0	—	V _{CC} × 0.12	
Power Supply Voltage	V _{CC}		4.75	5.0	5.25	
Program Power Supply Voltage	V _{PP}					
Address Access Time	t _{ACC}	V _{CC} = 5.0 ± 0.25 V	—	1.5 t _{cy} + 300	—	ns

Note: t_{cy} = 500 ns at 8 MHz



(2) High-Speed Programming Operation

Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
Input High Voltage	V_{IH4}		$V_{CC} \times 0.7$	—	V_{CC}	V
Input Low Voltage	V_{IL4}		0	—	$V_{CC} \times 0.12$	
Power Supply Voltage	V_{CC}		6.0	6.25	6.5	
Program Power Supply Voltage	V_{PP}		12.5	12.75	13.0	
Initial Program Pulse Width	t_{PW}	$V_{CC} = 6.0 \text{ V}$	0.095	0.1	0.105	ms



Note1: When V_{CC} power supply is turned on or after, V_{PP} must be increased.

When V_{CC} power supply is turned off or before, V_{PP} must be increased.

Note2: The device must not be set to the EPROM programmer or picked up from it under applying the program voltage ($12.75 \text{ V} \pm 0.25 \text{ V} \approx V$) to the V_{PP} pin as the device is damaged.

Note3: Be sure to execute the recommended programming mode with the recommended programming adaptor. If a mode or an adaptor except the above, the misoperation sometimes occurs.



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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